

SHINDENGEN

HVX-2 Series Power MOSFET

N-Channel Enhancement type

2SK2677

(FP10W90HVX2)

900V 10A

FEATURES

- Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.
- The static $R_{ds(on)}$ is small.
- The switching time is fast.
- Avalanche resistance guaranteed.

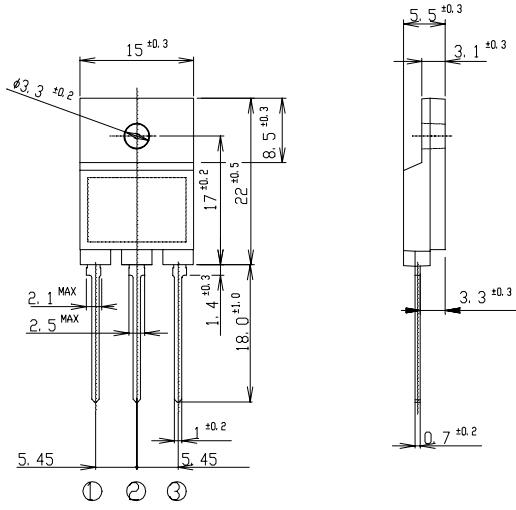
APPLICATION

- Switching power supply of AC 240V input
- High voltage power supply
- Inverter

OUTLINE DIMENSIONS

Case : ITO-3P

(Unit : mm)



①: G

②: D

③: S

RATINGS

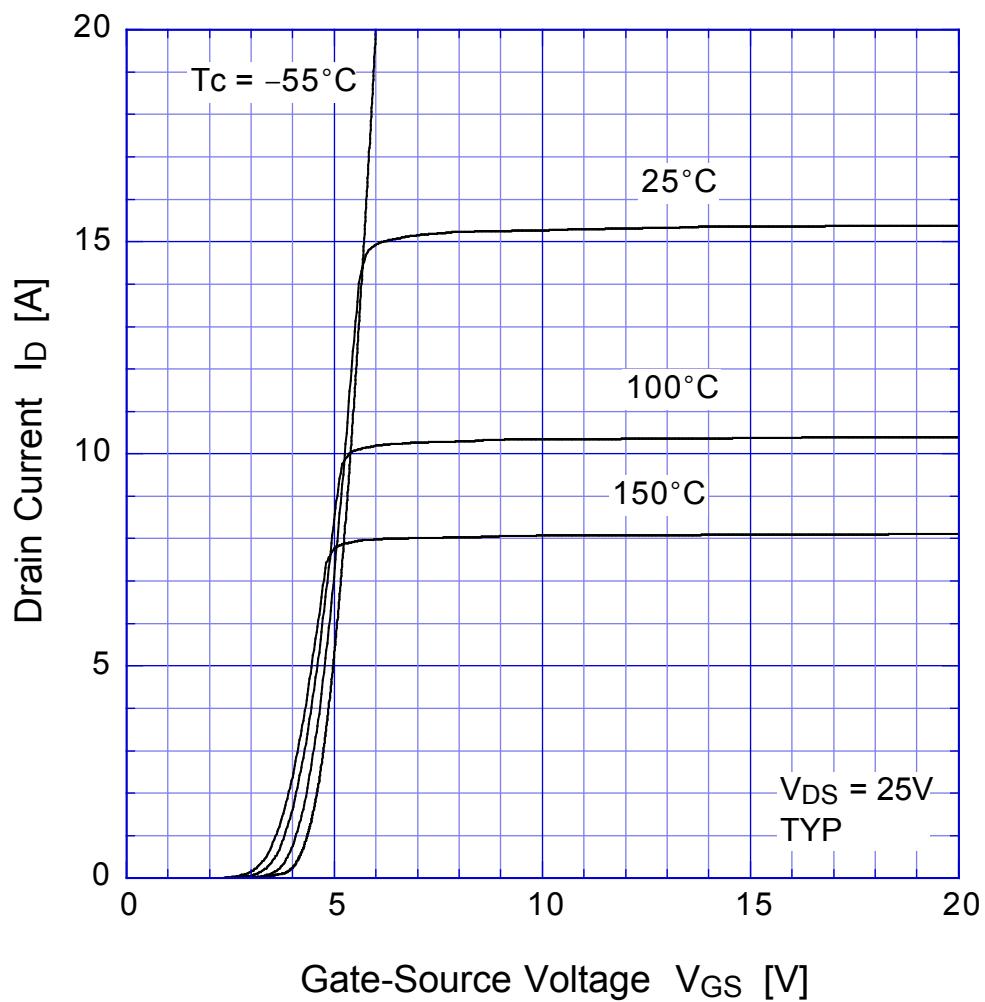
● Absolute Maximum Ratings (T_c = 25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55~150	°C
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		900	V
Gate-Source Voltage	V _{GSS}		±30	
Continuous Drain Current (DC)	I _D		10	A
Continuous Drain Current (Peak)	I _{DP}	Pulse width ≤ 10 μ s, Duty cycle ≤ 1/100	20	
Continuous Source Current (DC)	I _S		10	
Total Power Dissipation	P _T		65	W
Repetitive Avalanche Current	I _{AR}	T _{ch} = 150°C	10	A
Single Avalanche Energy	E _{AS}	T _{ch} = 25°C	260	mJ
Repetitive Avalanche Energy	E _{AR}	T _{ch} = 25°C	26	
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	T _{OR}	(Recommended torque : 0.5 N·m)	0.8	N·m

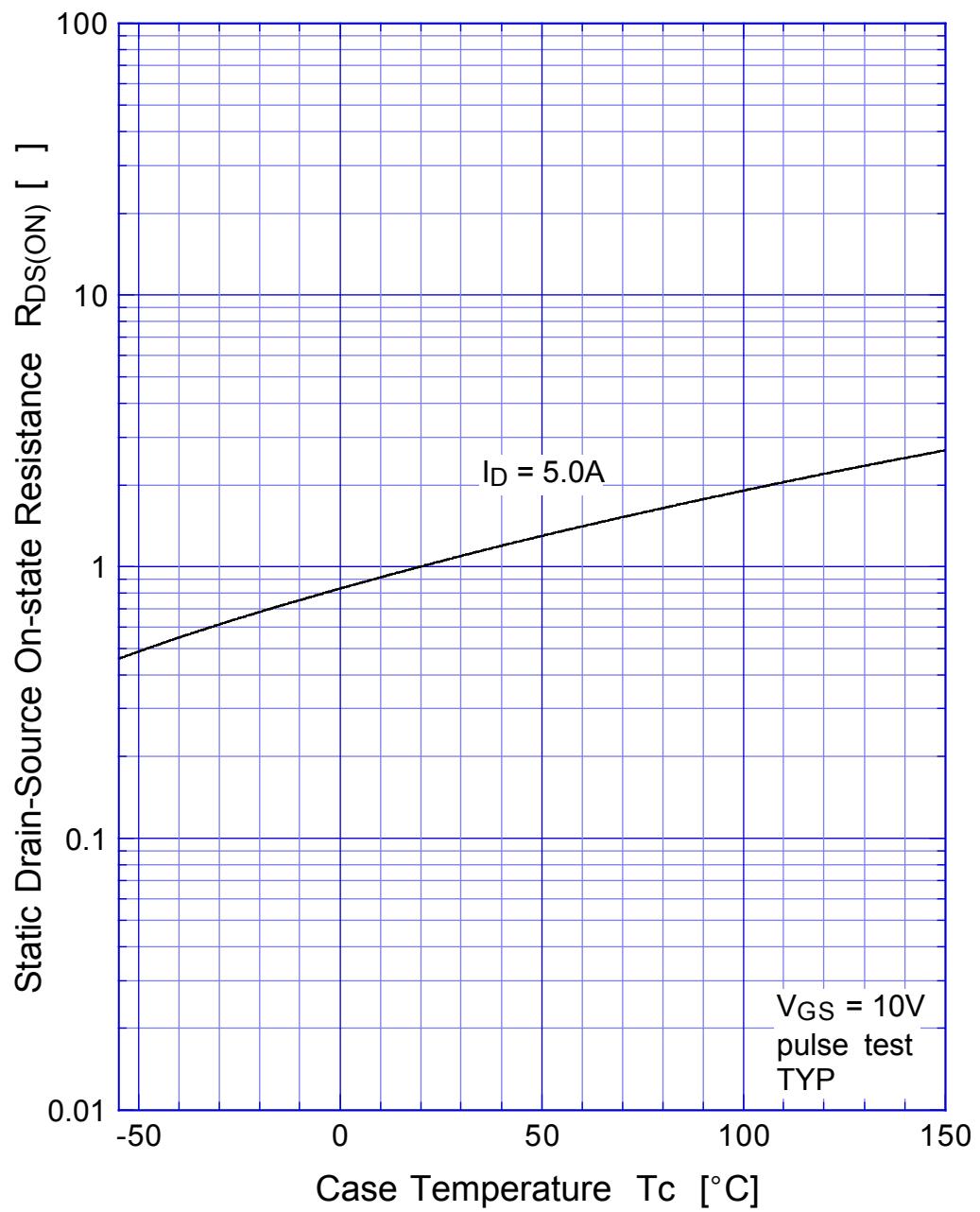
●Electrical Characteristics T_c = 25°C

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, VGS = 0V	900			V
Zero Gate Voltage Drain Current	I _{DSS}	VDS = 900V, VGS = 0V			250	μA
Gate-Source Leakage Current	I _{GSS}	VGS = ±30V, VDS = 0V			±0.1	
Forward Transconductance	g _{fS}	ID = 5A, VDS = 10V	4.8	8.0		S
Static Drain-Source On-state Resistance	R _{D(S)ON}	ID = 5A, VGS = 10V		1.05	1.4	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, VDS = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V _{SD}	I _S = 5A, VGS = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			1.92	°C/W
Total Gate Charge	Q _g	VDD = 400V, VGS = 10V, ID = 10A		90		nC
Input Capacitance	C _{iss}	VDS = 25V, VGS = 0V, f = 1MHz		2150		pF
Reverse Transfer Capacitance	C _{rss}			50		
Output Capacitance	C _{oss}			210		
Turn-On Time	t _{on}	ID = 5A, RL = 30Ω, VGS = 10V		140	250	ns
Turn-Off Time	t _{off}			440	740	

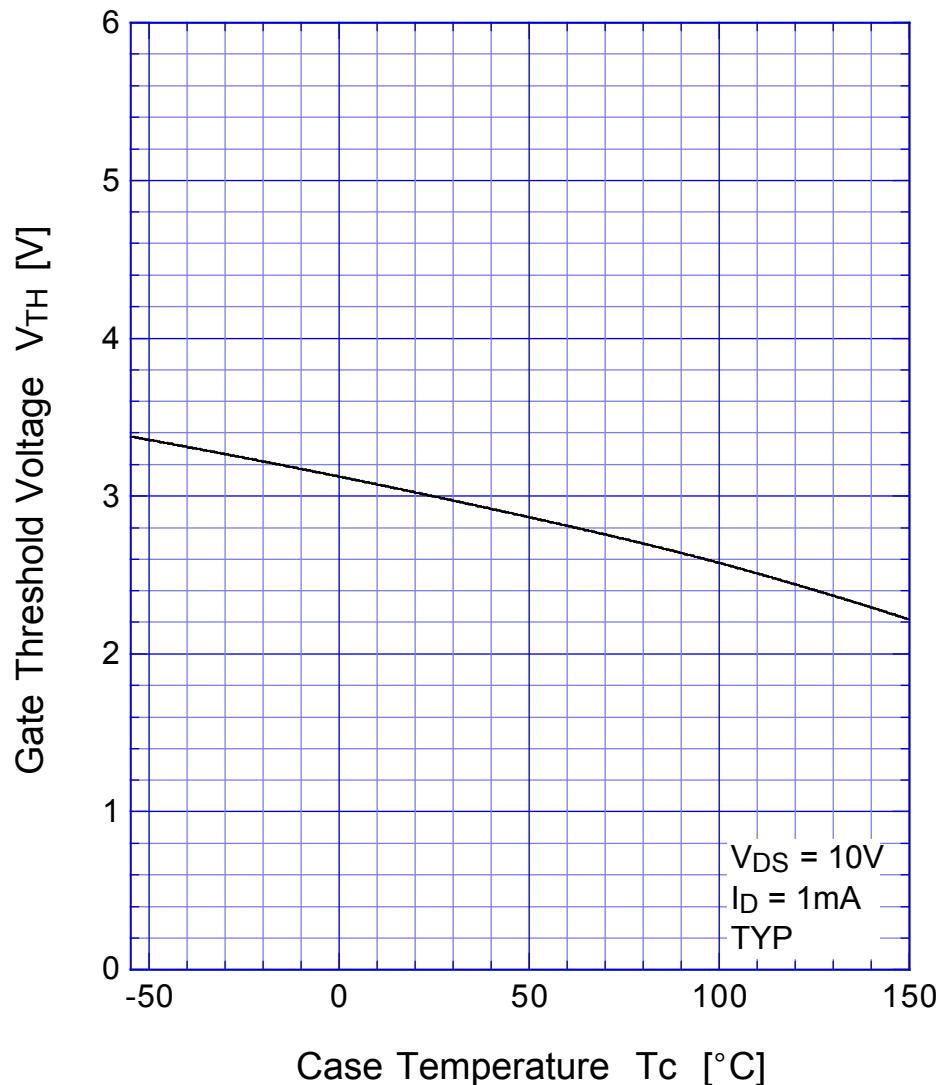
2SK2677 Transfer Characteristics



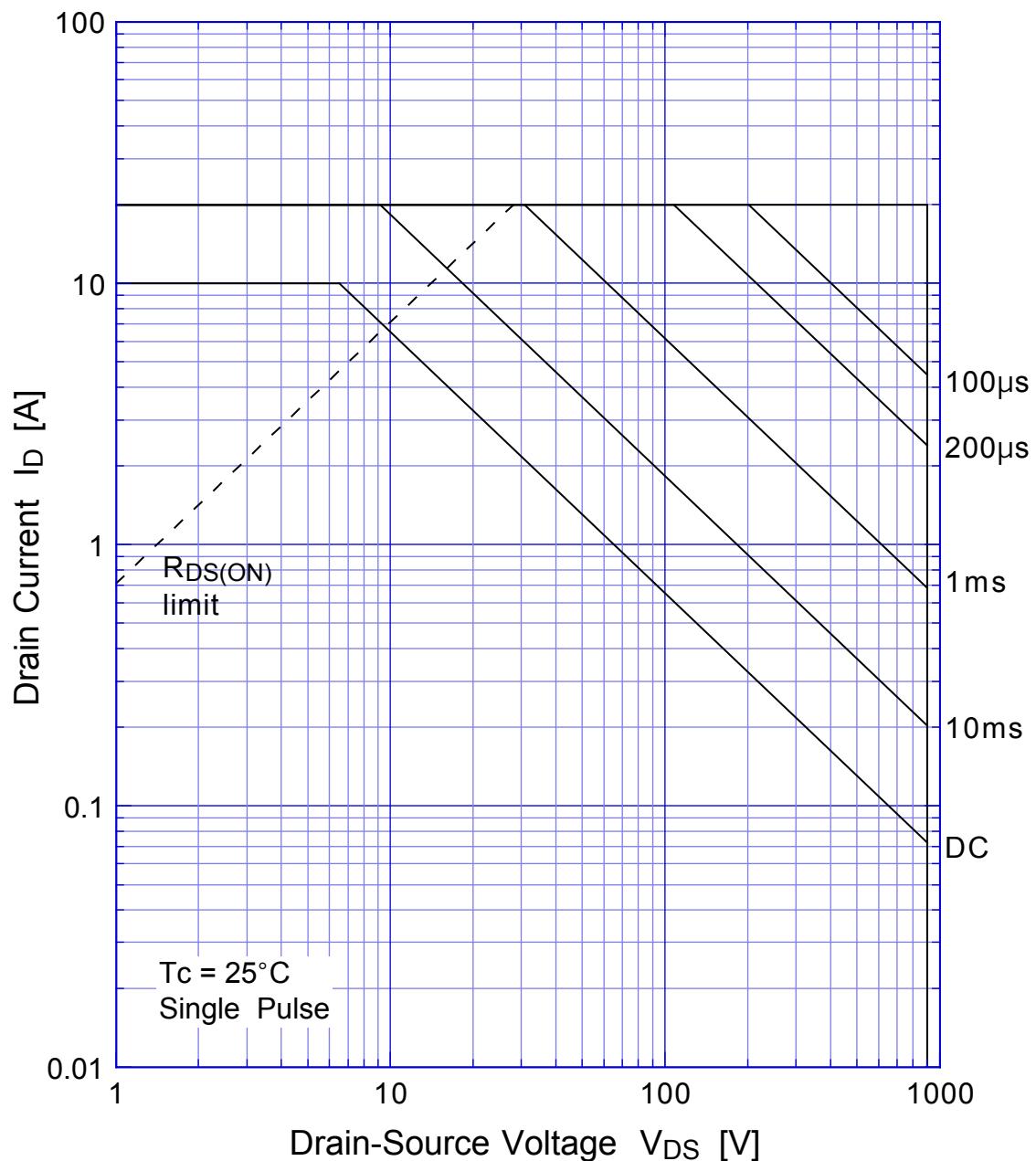
2SK2677 Static Drain-Source On-state Resistance



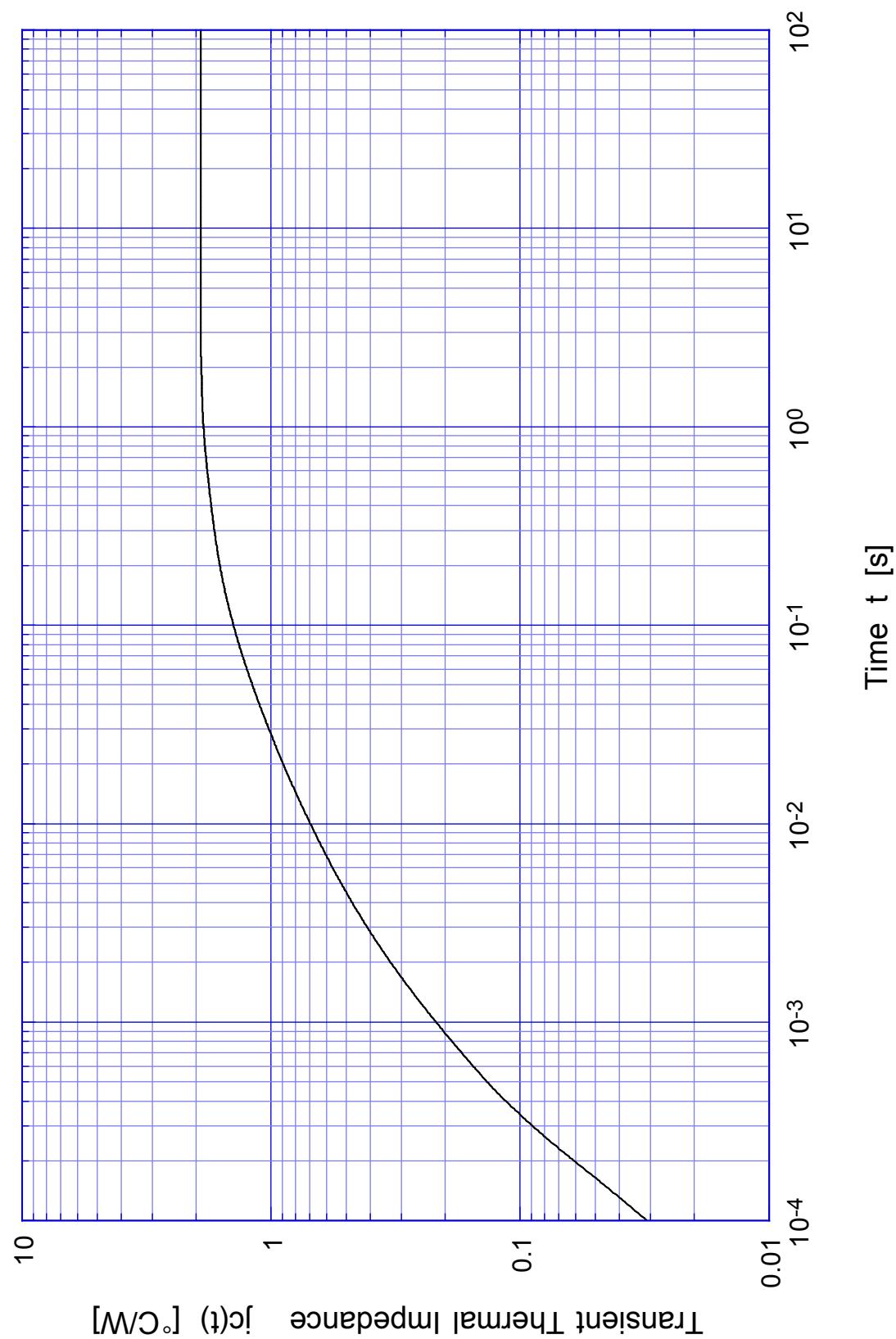
2SK2677 Gate Threshold Voltage



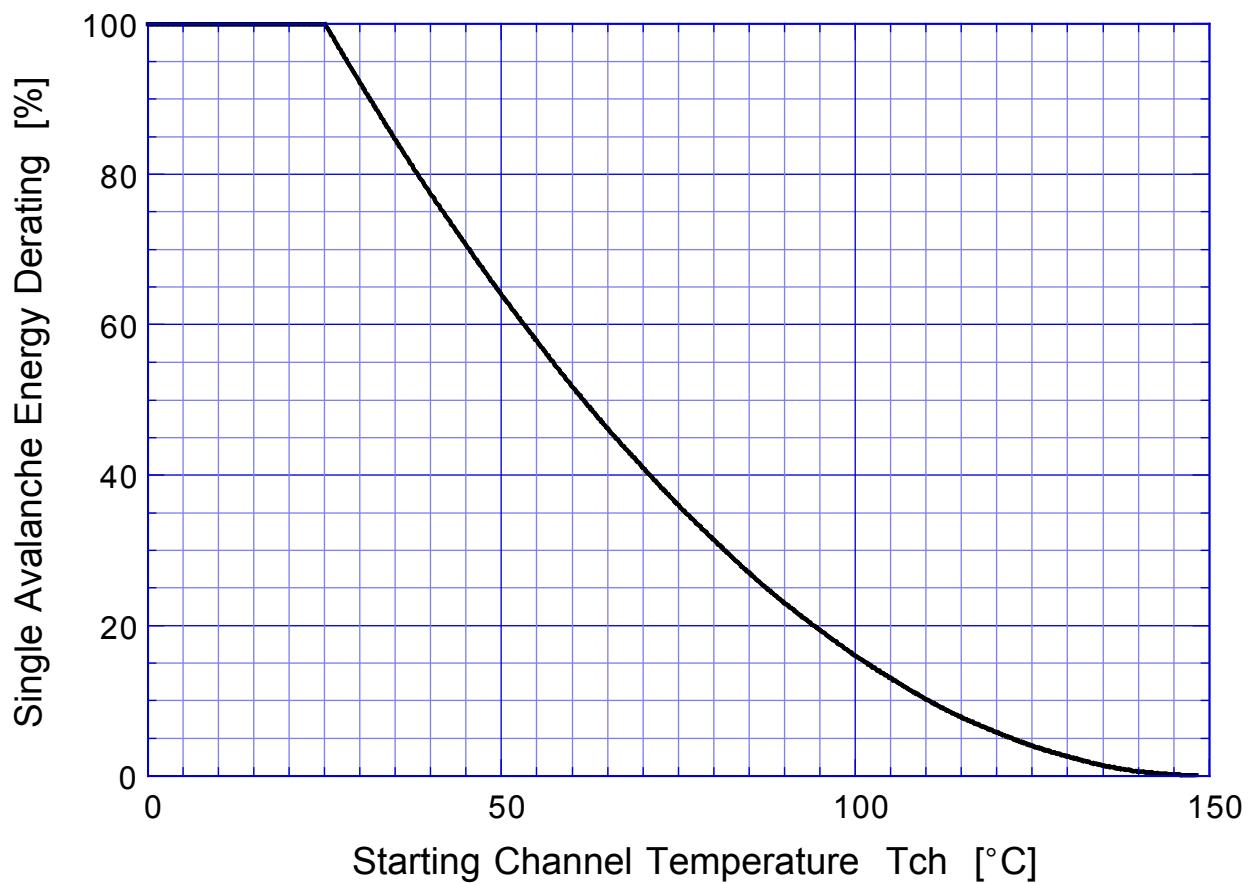
2SK2677 Safe Operating Area



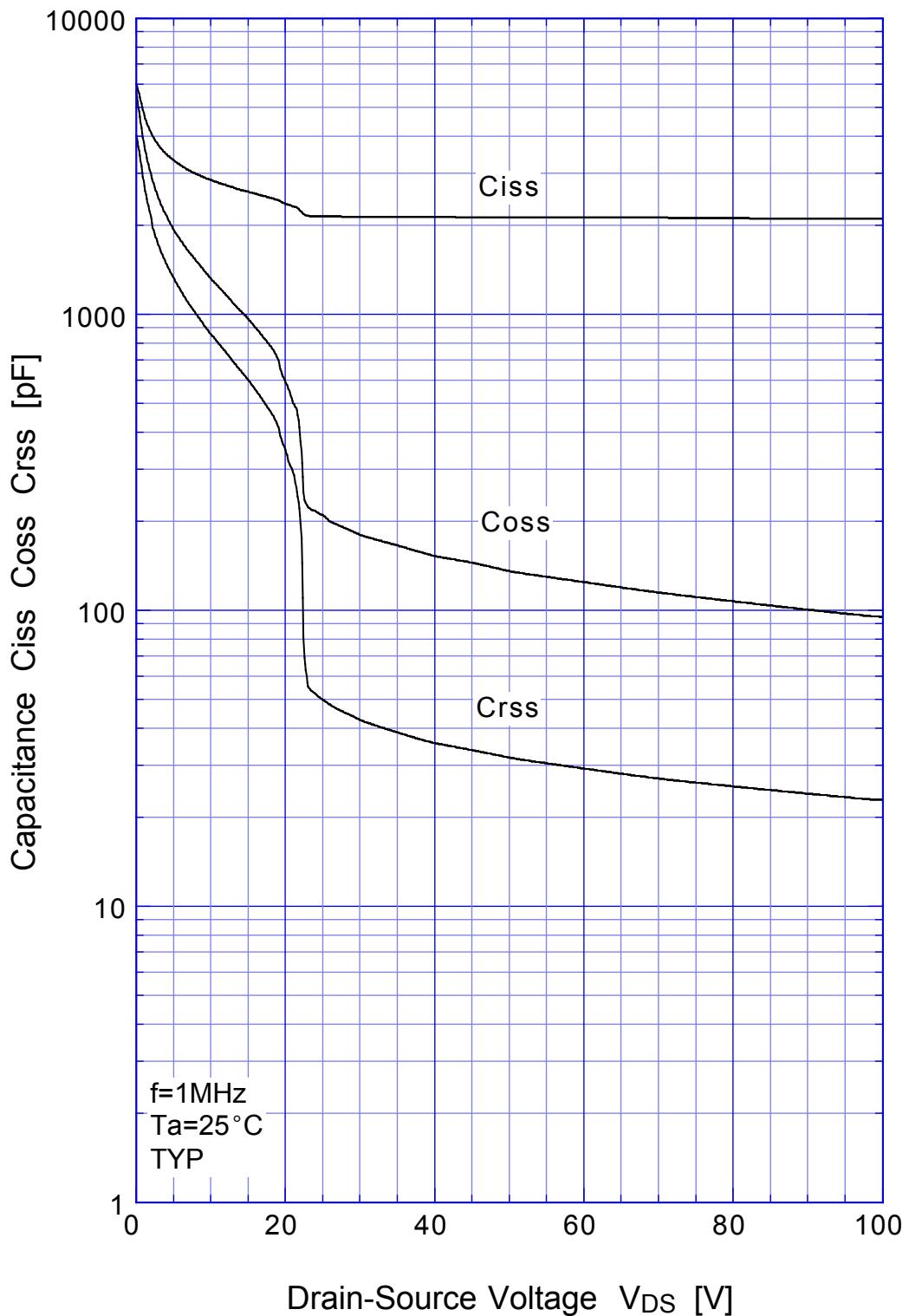
2SK2677 Transient Thermal Impedance



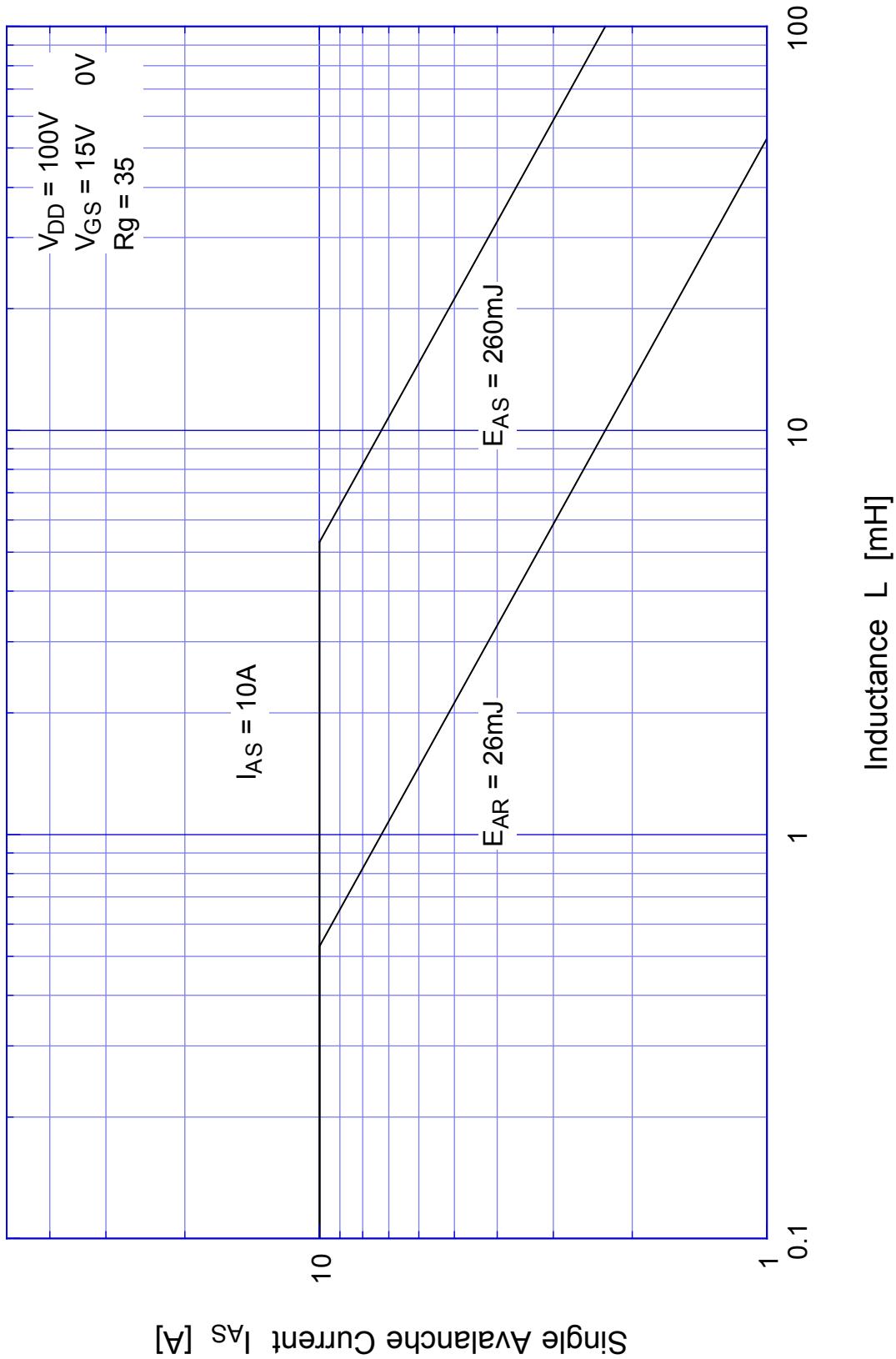
2SK2677 Single Avalanche Energy Derating



2SK2677 Capacitance

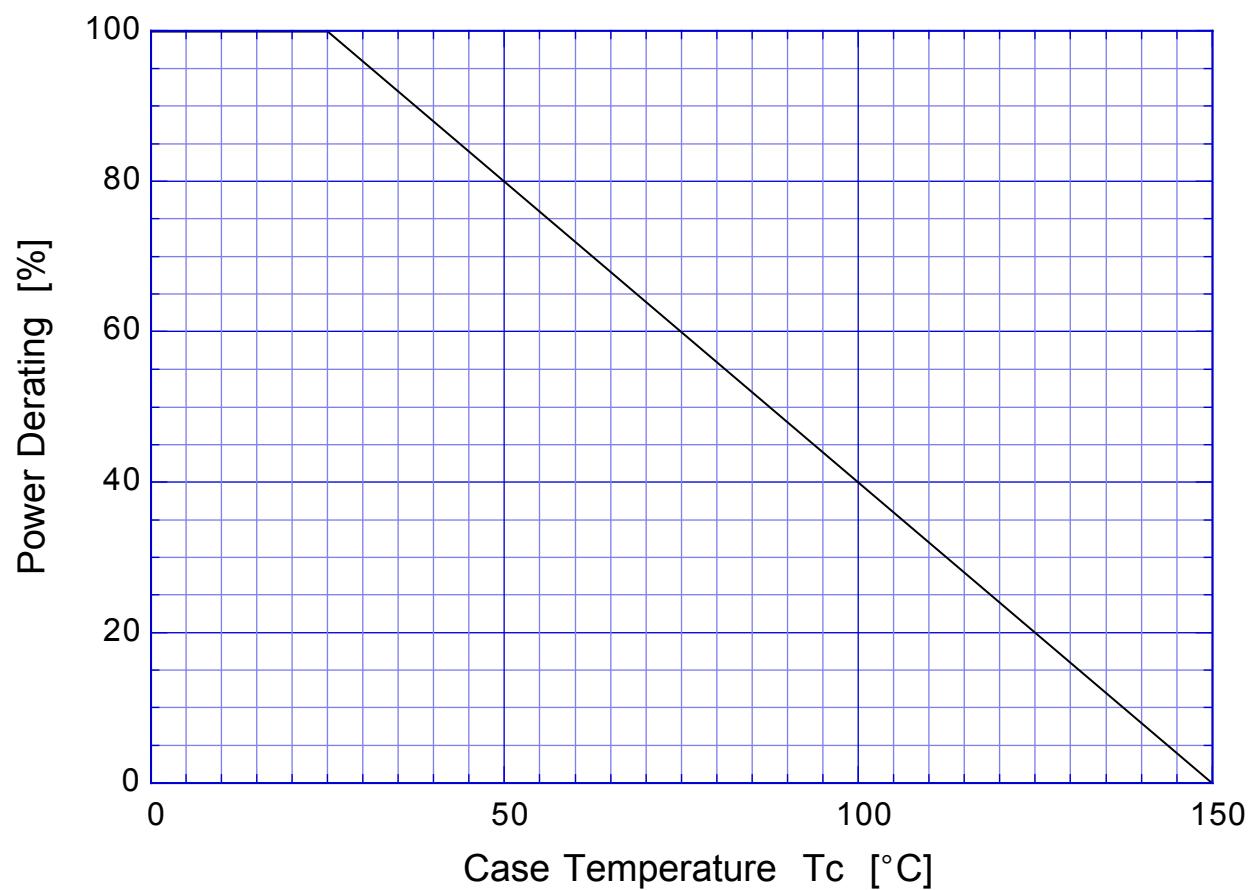


2SK2677 Single Avalanche Current - Inductive Load



2SK2677

Power Derating



2SK2677

Gate Charge Characteristics

